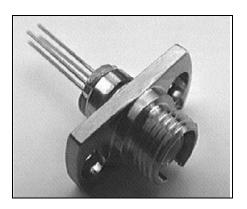


# Low Power 1550 nm FP Laser in FC Receptacle Package

STL81007x

#### **Features**

- · Designed for applications in fiber optic networks
- Laser Diode with Multi-Quantum Well structure
- Suitable for bit rates up to 1 Gbit/s
- Ternary Photodiode at rear mirror for monitoring and control of radiant power
- Hermetically sealed subcomponents, similar to TO 46
- SM receptacle with 2-hole flange and optional connector





# Pin Configuration and Flange

# Pin Configuration and Flange

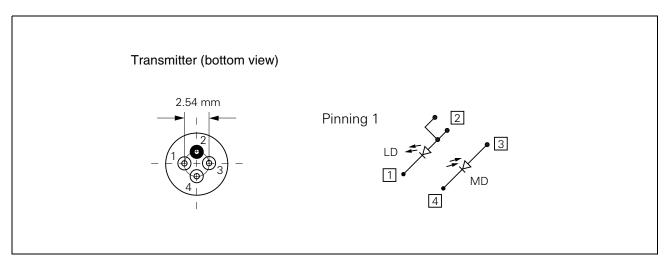


Figure 1 Transmitter

# **Available Pinnings with Flange**

Туре	Transmitter
STL81007x	1



Description

#### **Description**

#### Differences between a Fabry-Perot and a DFB Laserdiode

is longer than one wavelength, and a standing wave is created. The number n of half wavelengths  $\lambda$  is  $n=2\times\frac{L}{\lambda}$ . If L >>  $\lambda$  then we speak of a Fabry-Perot Laser because the laserdiode emits multi-longitudinal modes. Typically the laserdiode is 250 µm long. For  $\lambda=1310$  nm/1550 nm n is about 350. Therefore for many neighboring wavelengths the "standing wavelength" condition specified above is fulfilled. For a DFB-Laser a special grating acts as a distributed filter allowing only one of the cavity's longitudinal modes to propagate. This can be described with a reduced oscillator length  $\tilde{L}$  which is in the range of  $\lambda$ . For such a reduced oscillator length the standing wavelength condition will be fulfilled for n  $\approx$  2 what means for only one wavelength.

A conventional laser consists of an amplifying medium and two end mirrors. The cavity

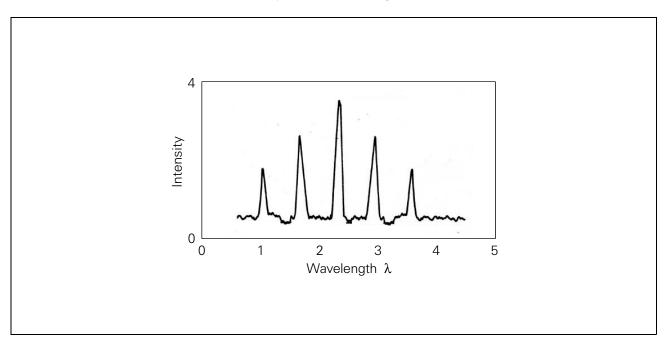


Figure 2 Fabry-Perot Laserdiode



# **Description**

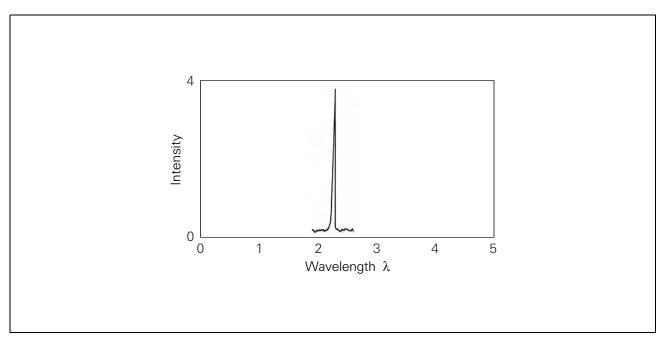


Figure 3 DFB Laserdiode

# **Regulatory Compliance**

Feature	Standard	Comments
Electrostatic Discharge (ESD) to the Electrical Pins	MIL-STD 883D Method 3015.7	Class 1 (<500 V)



#### **Technical Data**

#### **Technical Data**

### **Absolute Maximum Ratings**

Parameter	Symbol	Limit Values		Unit
		min.	max.	
Module				
Operating temperature range at case	$T_{C}$	-40	85	°C
Storage temperature range	$T_{ m stg}$	-40	85	
Soldering temperature ( $t_{max} = 10 \text{ s}$ , 2 mm distance from bottom edge of case)	$T_{S}$		260	
Laser Diode				
Direct forward current	$I_{Fmax}$		120	mA
Radiant power CW	$P_{F, rad}$		1	mW
Reverse Voltage	$V_{R}$		2	V
Monitor Diode				
Reverse Voltage	$V_{R}$		10	V
Forward Current	$I_{F}$		2	mA

The electro-optical characteristics described in the following tables are only valid for use within the specified maximum ratings or under the recommended operating conditions.

# **Transmitter Electro-Optical Characteristics**

Parameter	Symbol	Limit Values			Unit	
		min.	typ.	max.		
Optical output power (maximum)	P <sub>F, max</sub>	0.4			mW	
Emission wavelength center of range, $P_{\rm F}$ = 0.5 $P_{\rm F, max.}$	$\lambda_{trans}$	1510		1590	nm	
Spectral width (RMS)	$\sigma_{\lambda}$			5		
Temperature coefficient of wavelength	TC			0.5	nm/K	
Threshold current (whole temperature range)	$I_{th}$	2		55	mA	
Forward voltage, $P_{\rm F} = 0.5 P_{\rm F, max.}$	$V_{F}$			1.5	V	
Radiant power at $I_{th}$	$P_{th}$			10	μW	



#### **Technical Data**

### Transmitter Electro-Optical Characteristics (cont'd)

Parameter	Symbol		ues	Unit	
		min.	typ.	max.	
Slope efficiency (–4085°C)	η	8		60	mW/A
Variation of 1st derivative of P/I (0.05 to 0.4 mW)	$S_{var}$	-30		30	%
Differential series resistance	$R_{S}$			8	Ω
Rise time (10%–90%)	$t_{r}$		100	200	ps
Fall time (10%–90%)	$t_{f}$		270	500	

### **Monitor Diode Electro-Optical Characteristics**

Parameter	Symbol	Limit Values		Unit
		min.	max.	
Dark current, $V_{R}$ = 5 V, $P_{F}$ = 0, $T$ = $T_{max}$	$I_{R}$		500	nA
Photocurrent, $V_{R} = 5 \text{ V}$ , $P_{F} = 0.5 P_{F, \text{max}}$	$I_{P}$	100	1000	μΑ
Capacitance, $V_R = 5 \text{ V}, f = 1 \text{ MHz}$	$C_5$		10	pF
Tracking error <sup>1)</sup> , $V_{R} = 5 \text{ V}$	TE	-1	1	dB

The tracking error TE is the maximum deviation of  $P_{\rm F}$  at constant current  $I_{\rm mon}$  over a specified temperature range and relative to the reference point:  $I_{\rm mon, \, ref} = I_{\rm mon}$  ( $T = 25^{\circ}$ C,  $P_{\rm F} = 0.5$   $P_{\rm F, \, max.}$ ). Thus, TE is given by:

$$TE[dB] = 10 \times log \frac{P_{F}[T_{C}]}{P_{F}[25^{\circ}C]}$$

#### **End of Life Time Characteristics**

Parameter	Symbol	Limit Values		Unit
		min.	max.	
Threshold current at $T = T_{\text{max}}$	$I_{th}$		60	mA
Current above threshold, over full temperature range, at $I_{\text{mon, ref}} = I_{\text{mon}}$ ( $T = 25^{\circ}\text{C}$ , $P_{\text{F}} = 0.5$ $P_{\text{F, max.}}$ , BOL)	$\Delta I_{F}$	7	70	
Tracking Error	TE	-1.5	1.5	dB
Monitor Dark Current, $V_R = 2 \text{ V}$ , $T = T_{\text{max}}$	$I_{R}$		1	μΑ



**Fiber Data** 

# **Fiber Data**

The mechanical fiber characteristics are described in the following table.

### **Fiber Characteristics**

Parameter		Limit Values		
	min.	typ.	max.	
Mode Field Diameter	8	9	10	μm
Cladding Diameter	123	125	127	
Mode Field/Cladding Concentricity Error			1	
Cladding Non-circularity			2	%
Mode Field Non-circularity			6	
Cut off Wavelength	1270			nm
Jacket Diameter	0.8		1	mm
Bending Radius	30			
Tensile Strength Fiber Case	5			N
Length	0.8		1.2	m



**Eye Safety** 

#### **Eye Safety**

Ensure to avoid exposure of human eyes to high power laser diode emitted laser beams. Especially do not look directly into the laser diode or the collimated laser beam when the diode is activated.

#### Class 3B Laser Product According to IEC 60825-1

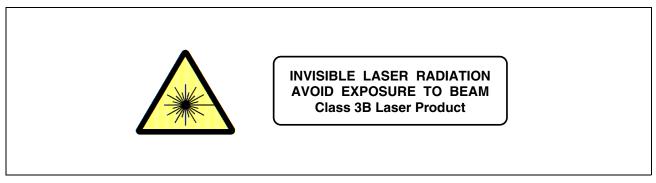


Figure 4 Required Labels

# Class IIIb Laser Product According to FDA Regulations Complies with 21 CFR 1040.10 and 1040.11



Figure 5 Required Label

#### **Laser Data**

Wavelength	1550 nm
Maximum total output power	less than 50 mW
Beam divergence (1/e²)	10°



# **Package Outlines**

# **Package Outlines**

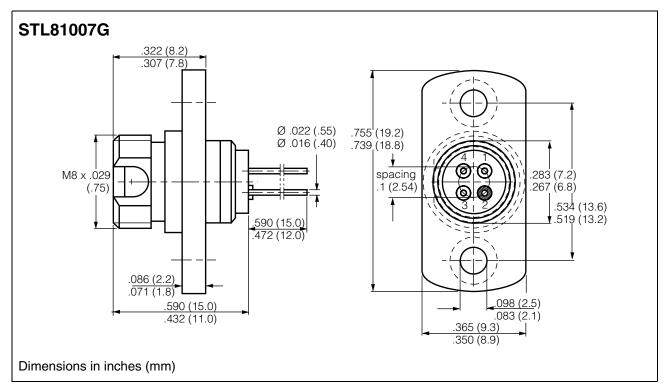


Figure 6

# **Flange Options**

Model	Туре
STH51007G	SM FC Receptacle Package

#### STL81007x

Revision	History:	2002-01-01	DS0
Previous	Version:		
Page	Subjects	(major changes since last revision)	
	Documen	t's layout has been changed: 2002-Aug.	

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